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- Meet or Exceed EIA Standard RS-485
- Designed for High-Speed Multipoint Transmission on Long Bus Lines in Noisy Environments
- Support Data Rates up to and Exceeding Ten Million Transfers Per Second
- Common-Mode Output Voltage Range of –7 V to 12 V
- Positive- and Negative-Current Limiting
- Low Power Consumption . . . 1.5 mA Max (Output Disabled)
- Functionally Interchangeable With SN75172

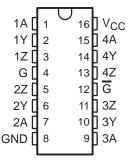
# description

The SN65LBC172 and SN75LBC172 are monolithic quadruple differential line drivers with 3-state outputs. Both devices are designed to meet the requirements of EIA Standard RS-485. These devices are optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. Each driver features wide positive and negative commonmode output voltage ranges, current limiting, and thermal-shutdown circuitry making it suitable for party-line applications in noisy environments. Both devices are designed using LinBiCMOS™, facilitating ultra-low power consumption and inherent robustness.

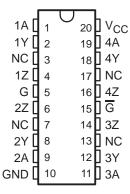
Both the SN65LBC172 and SN75LBC172 provide positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. These devices offer optimum performance when used with the SN75LBC173 or SN75LBC175 quadruple line receivers. The SN65LBC172 and SN75LBC172 are available in the 16-pin DIP package (N) and the 20-pin wide-body small-outline inline-circuit (SOIC) package (DW).

The SN75LBC172 is characterized for operation over the commercial temperature range of 0°C to 70°C. The SN65LBC172 is characterized over the industrial temperature range of -40°C to 85°C.

#### N PACKAGE (TOP VIEW)



# DW PACKAGE (TOP VIEW)



NC - No internal connection

# FUNCTION TABLE (each driver)

| INPUT | ENABLES |   | OUTPUTS |   |  |
|-------|---------|---|---------|---|--|
| Α     | G       | G | Υ       | Z |  |
| Н     | Н       | Χ | Н       | L |  |
| L     | Н       | X | L       | Н |  |
| Н     | Х       | L | Н       | L |  |
| L     | Х       | L | L       | Н |  |
| X     | L       | Н | Z       | Z |  |

H = high level, L = low level,

X = irrelevant, Z = high impedance (off)



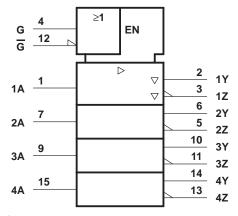
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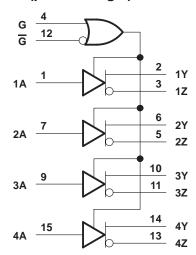
# logic symbol<sup>†</sup>



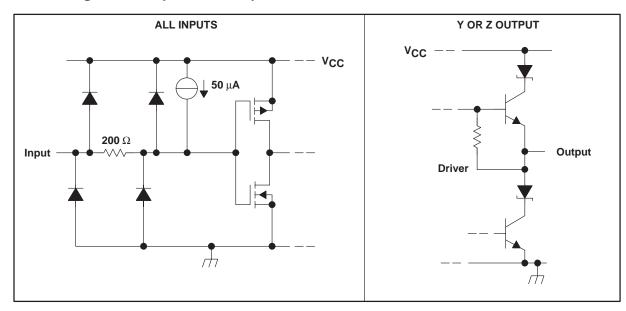
<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the N package.

# logic diagram (positive logic)



# schematic diagrams of inputs and outputs



# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

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# absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

| Supply voltage range, V <sub>CC</sub> (see Note 1)                | 0.3 V to 7 V                    |
|---|---------------------------------|
| Output voltage range, VO  |                                 |
| Input voltage range, V <sub>I</sub>                               | 0.3 V to 7 V                    |
| Continuous power dissipation                                      | Internally limited <sup>‡</sup> |
| Operating free-air temperature range, T <sub>A</sub> : SN65LBC172 | –40°C to 85°C                   |
| SN75LBC172  | 0°C to 70°C                     |
| Storage temperature range, T <sub>stq</sub>                       | –65°C to 150°C                  |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds      |                                 |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions

|  |            | MIN | NOM        | MAX       | UNIT    |
|--|------------|-----|------------|-----------|---------|
| Supply voltage, V <sub>CC</sub>                              |            |     | 5          | 5.25      | V       |
| High-level input voltage, V <sub>IH</sub>                    |            |     |            |           | V       |
| Low-level input voltage, V <sub>IL</sub>                     |            |     |            | 0.8       | V       |
| Valtage at any bus terminal (congretal), or common mode). Va | Y or Z     |     |            | 12        | V       |
| Voltage at any bus terminal (separately or common mode), VO  | Y OF Z     |     |            | -7        | V       |
| High-level output current, IOH                               | Y or Z     |     | -60        |           | mA      |
| Low-level output current, IOL                                | Y or Z     |     | 60         |           | mA      |
| Continuous total power dissipation                           |            |     | Dissipatio | on Rating | g Table |
| One wating free air temperature T.                           | SN65LBC172 | -40 |            | 85        | °C      |
| Operating free-air temperature, T <sub>A</sub>               | SN75LBC172 | 0   |            | 70        |         |

### **DISSIPATION RATING TABLE**

| PACKAGE | $T_{\mbox{$A$}} \leq 25^{\circ}\mbox{$C$}$ POWER RATING | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|---------|---|--|---------------------------------------|---------------------------------------|
| DW      | 1125 mW   | 9.0 mW/°C                                      | 720 mW                                | 585 mW                                |
| N       | 1150 mW   | 9.2 mW/°C                                      | 736 mW                                | 598 mW                                |



<sup>&</sup>lt;sup>‡</sup> The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature. NOTE 1: All voltage values are with respect to GND.

# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

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# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

| PARAMETER         |  | TEST CONDITIONS                                |                                       | MIN | TYP <sup>†</sup> | MAX     | UNIT |
|-------------------|--|--|---------------------------------------|-----|------------------|---------|------|
| VIK               | Input clamp voltage                                | $I_{I} = -18 \text{ mA}$                       |                                       |     |                  | -1.5    | V    |
|                   | Differential output voltage <sup>‡</sup>           | R <sub>L</sub> = 54 $\Omega$ ,<br>See Figure 1 | SN65LBC172                            | 1.1 | 1.8              | 5       | V    |
| 11/2-1            |  |  | SN75LBC172                            | 1.5 | 1.8              | 5       |      |
| IVODI             |  | $R_1 = 60 \Omega$                              | SN65LBC172                            | 1.1 | 1.7              | 5       |      |
|                   |  | See Figure 2                                   | SN75LBC172                            | 1.5 | 1.7              | 5       |      |
| Δ V <sub>OD</sub> | Change in magnitude of common-mode output voltage§ |  |                                       |     |                  | ±0.2    | V    |
| Voc               | Common-mode output voltage                         | R <sub>L</sub> = 54 Ω,                         | See Figure 1                          |     |                  | 3<br>-1 | ٧    |
| Δ Vocl            | Change in magnitude of common-mode output voltage§ | 1  |                                       |     |                  | ±0.2    | V    |
| IO                | Output current with power off                      | $V_{CC} = 0$ ,                                 | $V_0 = -7 \text{ V to } 12 \text{ V}$ |     |                  | ±100    | μΑ   |
| loz               | High-impedance-state output current                | V <sub>O</sub> = -7 V to 12 V                  |                                       |     |                  | ±100    | μΑ   |
| lіН               | High-level input current                           | V <sub>I</sub> = 2.4 V                         |                                       |     |                  | -100    | μΑ   |
| IIL               | Low-level input current                            | V <sub>I</sub> = 0.4 V                         |                                       |     |                  | -100    | μΑ   |
| los               | Short-circuit output current                       | V <sub>O</sub> = -7 V to 12 V                  |                                       |     |                  | ±250    | mA   |
| laa               | Supply current (all drivers)                       | No load  | Outputs enabled                       |     |                  | 7       | mA   |
| lcc               |  | INO IOAO                                       | Outputs disabled                      |     |                  | 1.5     | IIIA |

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

# switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

| PARAMETER           |                                     | TEST CONDITIONS        |              | MIN | TYP | MAX | UNIT |
|---------------------|-------------------------------------|------------------------|--------------|-----|-----|-----|------|
| t <sub>d</sub> (OD) | Differential output delay time      | R <sub>L</sub> = 54 Ω, | See Figure 3 | 2   | 11  | 20  | ns   |
| t <sub>t</sub> (OD) | Differential output transition time |                        | See Figure 3 | 10  | 15  | 25  | ns   |
| <sup>t</sup> PZH    | Output enable time to high level    | $R_L = 110 \Omega$ ,   | See Figure 4 |     |     | 30  | ns   |
| t <sub>PZL</sub>    | Output enable time to low level     | $R_L = 110 \Omega$ ,   | See Figure 5 |     |     | 30  | ns   |
| <sup>t</sup> PHZ    | Output disable time from high level | $R_L = 110 \Omega$ ,   | See Figure 4 |     |     | 50  | ns   |
| tPLZ                | Output disable time from low level  | $R_L = 110 \Omega$ ,   | See Figure 5 |     |     | 30  | ns   |

<sup>&</sup>lt;sup>‡</sup> The minimum V<sub>OD</sub> specification does not fully comply with EIA-485 at operating temperatures below 0°C. The lower output signal should be used to determine the maximum signal-transmission distance.

<sup>§ ∆|</sup>V<sub>OD</sub>| and ∆|V<sub>OC</sub>| are the changes in magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input changes from a high level to a low level.

#### PARAMETER MEASUREMENT INFORMATION

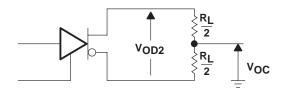
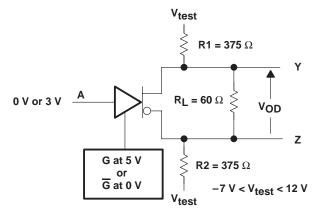
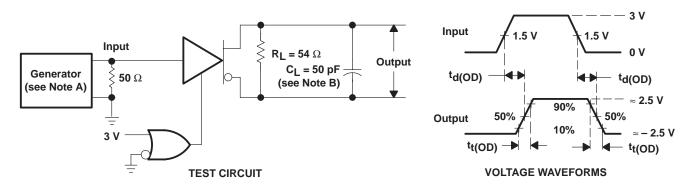


Figure 1. Differential and Common-Mode Output Voltages



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_{f} \leq$  5 ns,  $Z_{O} =$  50  $\Omega$ .
  - B. C<sub>L</sub> includes probe and stray capacitance.

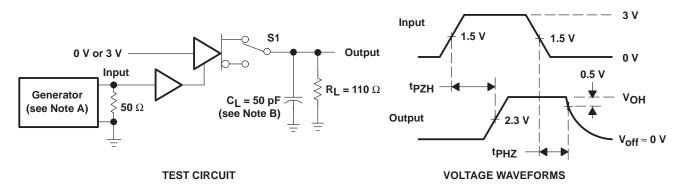
Figure 2. Driver V<sub>OD</sub> Test Circuit



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_f \leq$  5 ns,  $Z_O = 50 \ \Omega$ .
  - B. C<sub>L</sub> includes probe and stray capacitance.

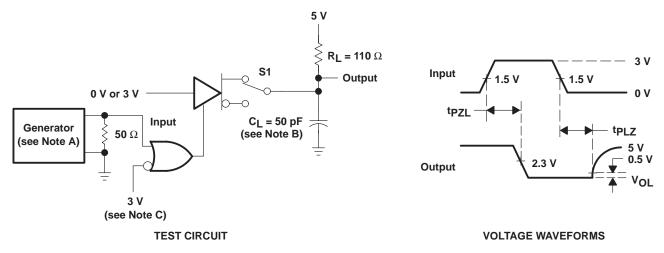
Figure 3. Driver Differential-Output Test Circuit and Delay and Transition-Time Waveforms

#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_{f} \leq$  5 ns,  $Z_{O} =$  50  $\Omega$ .
  - B. C<sub>I</sub> includes probe and stray capacitance.

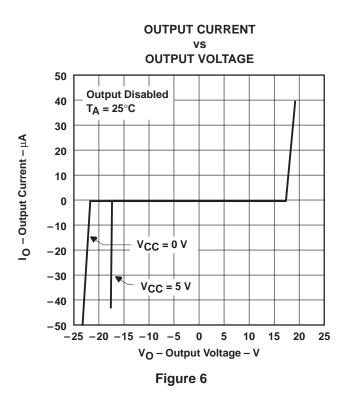
Figure 4. tpzH and tpHZ Test Circuit and Voltage Waveforms

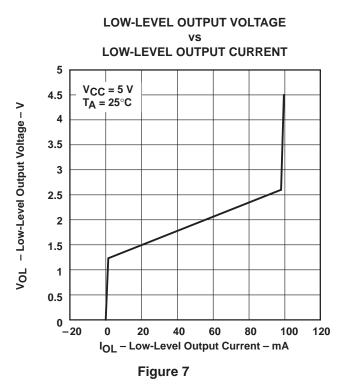


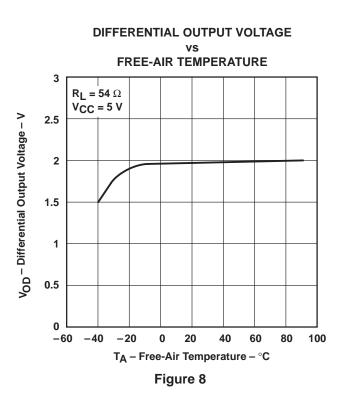
- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_{f} \leq$  5 ns,  $Z_{O} = 50 \ \Omega$ .
  - B. C<sub>L</sub> includes probe and stray capacitance.
  - C. To test the active-low enable  $\overline{G}$ , ground G and apply an inverted waveform to  $\overline{G}$ .

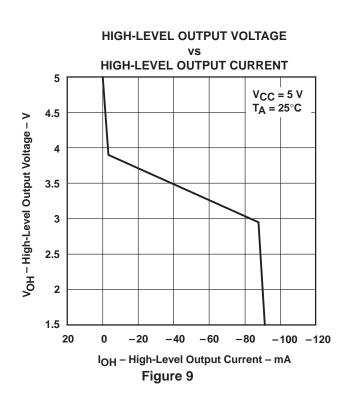
Figure 5. tpzL and tpLZ Test Circuit and Waveforms

#### **TYPICAL CHARACTERISTICS**

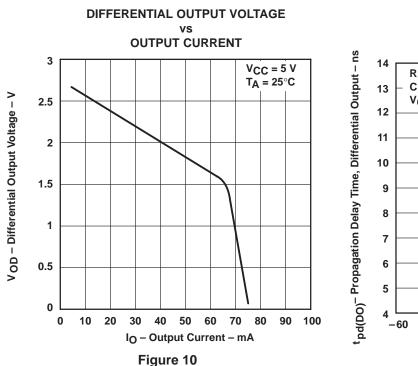


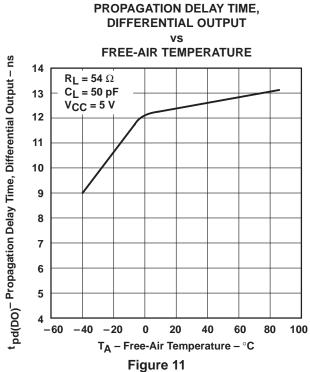






#### TYPICAL CHARACTERISTICS





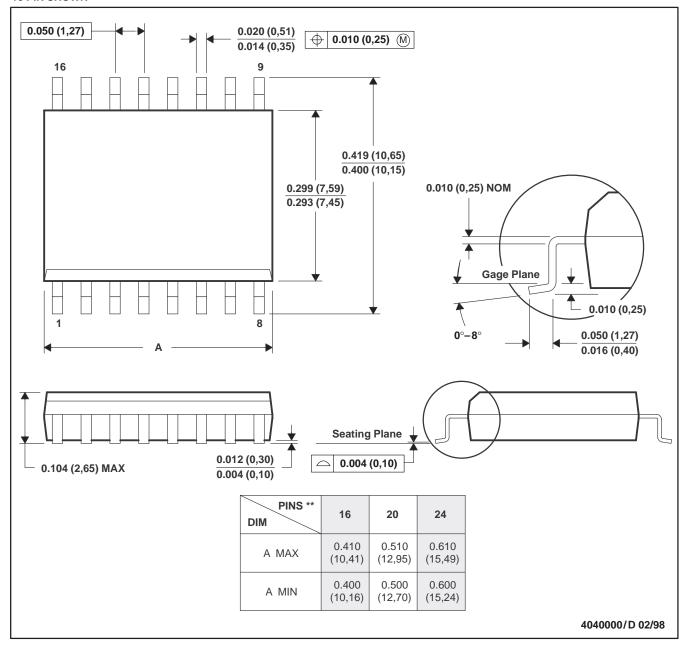
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#### **MECHANICAL DATA**

## DW (R-PDSO-G\*\*)

#### **16 PIN SHOWN**

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013



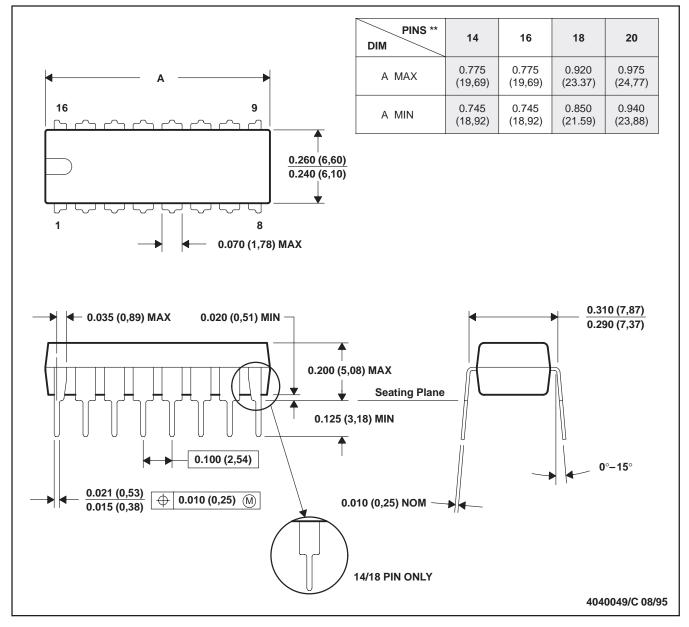
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#### **MECHANICAL DATA**

## N (R-PDIP-T\*\*)

#### **16 PIN SHOWN**

#### PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001.)

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